

HIGH-POWER PNP SILICON POWER TRANSISTORS

...designed for use in general-purpose amplifier and switching application .

FEATURES:

- * Recommend for 120W High Fiderity Audio Frequency Amplifier Output stage
- * Complementary to 2SC4029

PNP 2SA1553

15 AMPERE POWER TRANASISTOR

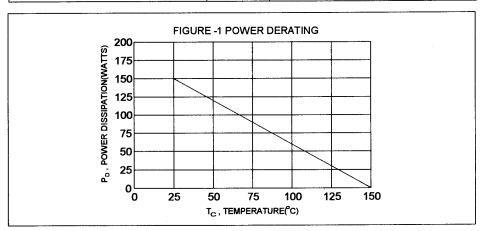
230 VOLTS 150 WATTS

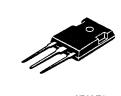
MAXIMUM RATINGS

| Characteristic | Symbol | 2SA1553 | Unit |
|---|----------------------------------|-------------|------|
| Collector-Emitter Voltage | V _{CEO} | 230 | V |
| Collector-Base Voltage | V _{CBO} | 230 | V |
| Emitter-Base Voltage | V _{EBO} | 5.0 | V |
| Collector Current - Continuous - Peak | I _C | 15 20 | A |
| Base current | I _B | 2.0 | Α |
| Total Power Dissipation @T _C = 25°C Derate above 25°C | P _D | 150 1.2 | W/°C |
| Operating and Storage Junction Temperature Range | T _J ,T _{STG} | -55 to +150 | °C |

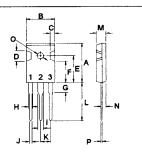
THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|-------------------------------------|--------|------|------|
| Thermal Resistance Junction to Case | Rθjc | 0.83 | °C/W |





TO-247(3P)



PIN 1.BASE 2.COLLECTOR 3.EMITTER

| DIM | MILLIMETERS | | | |
|-------|-------------|-------|--|--|
| Cilvi | MIN | MAX | | |
| Α | 20.63 | 22.38 | | |
| В | 15.38 | 16.20 | | |
| С | 1.90 | 2.70 | | |
| D | 5.10 | 6.10 | | |
| Ε | 14.81 | 15.22 | | |
| F | 11.72 | 12.84 | | |
| G | 4.20 | 4.50 | | |
| Н | 1.82 | 2.46 | | |
| 1 | 2.92 | 3.23 | | |
| J | 0.89 | 1.53 | | |
| K | 5.26 | 5.66 | | |
| L | 18.50 | 21.50 | | |
| M | 4.68 | 5.36 | | |
| N | 2.40 | 2.80 | | |
| 0 | 3.25 | 3.65 | | |
| Р | 0.55 | 0.70 | | |

MHz

| ELECTRICAL CHARACTERISTICS | (T | = 25°C | unless | otherwise | noted) |
|-----------------------------------|-----|--------|--------|-----------|--------|
|-----------------------------------|-----|--------|--------|-----------|--------|

| Characteristic | Symbol | Min | Max | Unit |
|---|-----------------------|----------|-----|------|
| OFF CHARACTERISTICS | | | | |
| Collector-Emitter Breakdown Voltage (I _C = 50 mA, I _B = 0) | V _(BR) CEO | 230 | | V |
| Collector Cutoff Current (V _{CB} = 230 V, I _E = 0) | І _{сво} | | 50 | uA |
| Emitter Cutoff Current (V _{EB} = 5.0 V, I _C = 0) | I _{EBO} | | 20 | uA |
| ON CHARACTERISTICS (1) | | | | |
| DC Current Gain (I _C = 1.0 A, V _{CE} = 5.0 V) * (I _C = 7.0 A, V _{CE} = 5.0 V) | hFE(2) hFE | 55 35 | 160 | |
| Collector-Emitter Saturation Voltage (I _C = 8.0 A,I _B = 800 mA) | V _{CE(sat)} | | 3.0 | V |
| Base-Emitter On Voltage | VBE(on) | | 1.5 | V |

 f_T

10

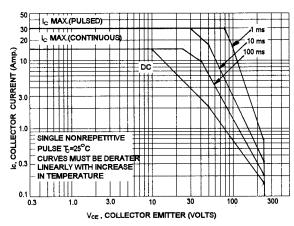
Current-Gain-Bandwidth Product

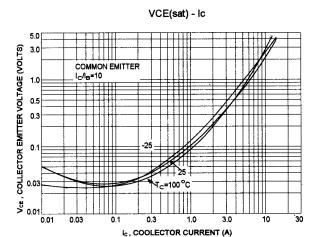
 $(I_C = 1.0 \text{ A}, V_{CE} = 5.0 \text{ V}, f = 1.0 \text{ MHz})$

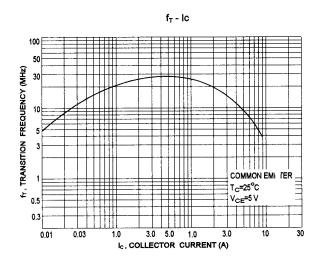
| | _ | | | | | _ |
|----|---|-----|----|---|-----|---|
| 55 | R | 110 | 80 | 0 | 160 | |

⁽¹⁾ Pulse Test: Pulse Width =300 us,Duty Cycle ≦ 2.0% * hFE(2) Classification :

ACTIVE REGION SAFE OPERATING AREA







DC CURRENT GAIN

